NSN 5961-01-477-3188

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-477-3188 **Inclosure Material:** Metal **Overall Length:** 2.960 inches **End Application:** E/ifscm electrical **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-205a (do-30) **Mounting Method:** Threaded stud **Overall Width Across Flats:** 1.060 inches **Thread Size:** 0.5000 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1600.0 repetitive peak reverse voltage **Current Rating Per Characteristic:** 150.00 amperes forward current, average **Maximum Operating Tempurature Per Measurement Point:** 180.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 insulated wire lead w/terminal lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: